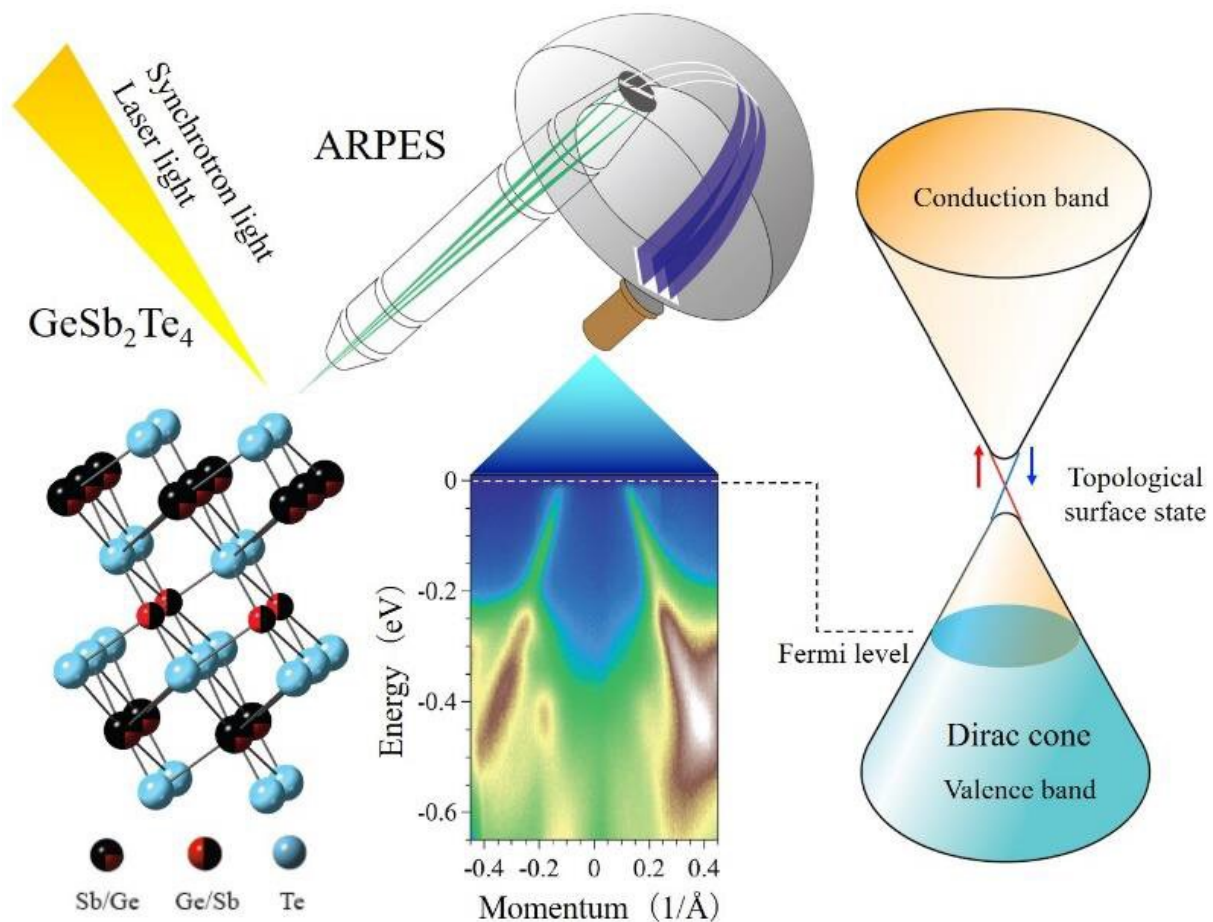


Discovery of massless electrons in phase-change materials provides next step for future electronics

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(Left) Crystal structure for the intermixed crystalline phase of the phase-change compound GeSb_2Te_4 . (Middle) Angle-resolved photoemission spectrum of crystalline GeSb_2Te_4 by showing the linearly dispersive band crossing the Fermi level. (Right) Schematic band structure of the crystalline GeSb_2Te_4 based on

this study Credit: Akio Kimura, Hiroshima University

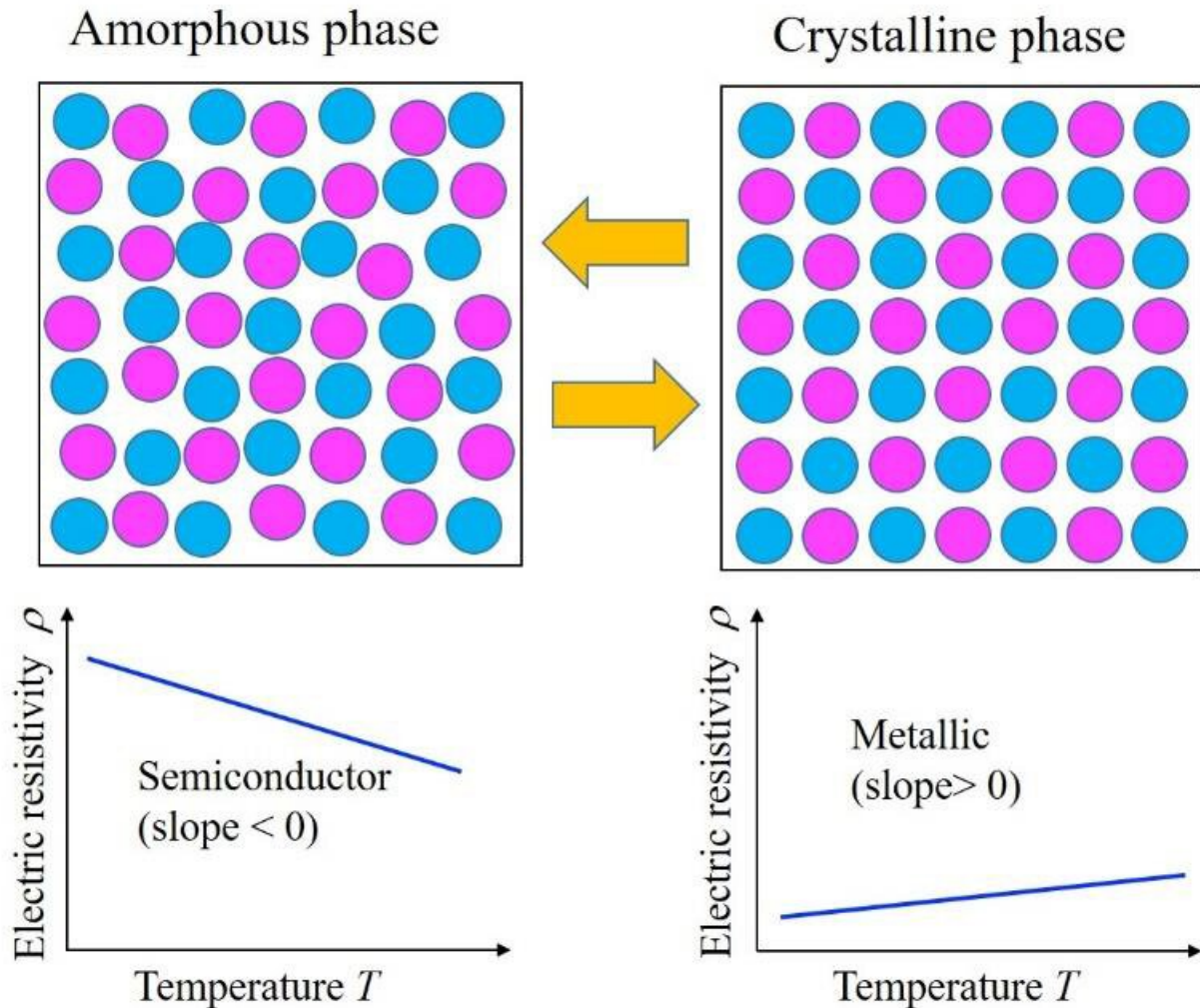
Researchers have found electrons that behave as if they have no mass, called Dirac electrons, in a compound used in rewritable discs, such as CDs and DVDs. The discovery of 'massless' electrons in this phase-change material could lead to faster electronic devices.

The international team published their results on July 6 in *ACS Nano*, a journal of the American Chemical Society.

The compound, GeSb_2Te_4 , is a phase-change material, meaning its atomic [structure](#) shifts from amorphous to crystalline under heat. Each structure has individual properties and is reversible, making the compound an ideal material to use in electronic devices where information can be written and rewritten several times.

"Phase-change materials have attracted a great deal of attention owing to the sharp contrast in optical and [electrical properties](#) between their two phases," said paper author Akio Kimura, professor in the Department of Physical Sciences in the Graduate School of Science and the Graduate School of Advanced Science and Engineering at Hiroshima University. "The [electronic structure](#) in the amorphous phase has already been addressed, but the experimental study of the electronic structure in the crystalline phase had not yet been investigated."

The researchers found that the crystalline phase of GeSb_2Te_4 has Dirac electrons, meaning it behaves similarly to graphene, a conducting material that consists of a single layer of carbon atoms. They also found that the surface of the crystalline structure shares characteristics with a topological insulator, where the internal structure remains static while the surface conducts electrical activity.



Schematic for the amorphous phase (left) and crystalline phase (right) of the phase-change materials which demonstrate the atomic rearrangement during the phase transition. The amorphous phase shows a semiconducting behavior with a large electrical resistivity while the crystalline phase behaves metallic with a much lower electrical resistivity. Credit: Akio Kimura, Hiroshima University

"The amorphous phase shows a semiconducting behavior with a large electrical resistivity while the crystalline phase behaves like a metallic

with a much lower electrical resistivity," said Munisa Nurmamat, paper author and assistant professor in the Department of Physical Sciences in the Graduate School of Science and the Graduate School of Advanced Science and Engineering at Hiroshima University. "The [crystalline phase](#) of GeSb_2Te_4 can be viewed as a 3-D analog of graphene."

Graphene is already considered by researchers to be a high-speed conducting material, according to Nurmamat and Kimura, but its inherently low on- and off-current ratio limits how it is applied in [electronic devices](#). As a 3-D version of [graphene](#), GeSb_2Te_4 combines speed with flexibility to engineer the next generation of electrical switching devices.

More information: Munisa Nurmamat et al, Topologically Nontrivial Phase-Change Compound GeSb_2Te_4 , *ACS Nano* (2020). [DOI: 10.1021/acsnano.0c04145](#)

Provided by Hiroshima University

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